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solutions for white light emitting diodesTianchun Lang, ab Tao Han, ab ** Cong Zhao, Shixiu Cao, Shuangqiang Fang, Shuai Li, Lei Zhao, Vladimir I. Korepanov and Alexey N. Yakovlev

transfer of $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}:Ce^{3+}$ solid

Color-tunable photoluminescence and energy

 $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}:Ce^{3+}$ solid solution phosphors were synthesized by introducing the isostructural $Mn_3Al_2(SiO_4)_3$ (MAS) into $Tb_3Al_5O_{12}:Ce^{3+}$ (TbAG). Under 456 nm excitation, $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}:Ce^{3+}$ shows energy transfers (ET) in the host, which can be obtained from the red emission components to enhance color rendering. Moreover, $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}:Ce^{3+}$ (x=0-0.2) exhibits substantial spectral broadening (68 \rightarrow 86 nm) due to the 5d \rightarrow 4f transition of Ce^{3+} and the Ce^{4-} transition of Ce^{4-} and the Ce^{4-} transition of Ce^{4-} transition of Ce^{4-} and the value reach approximately 32% at Ce^{4-} due to the 4fferent characteristics of luminescence evolution based on the effect of structural variation by substituting the Ce^{4-} pair for the larger Ce^{4-} pair. Therefore, with structural evolution, the luminescence of the solid solution phosphors could be tuned from yellow to orange-red, tunable by increasing the content of MAS for the applications of white light emitting diodes (WLED).

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Introduction

Nowadays, white light emitting diodes (wLEDs), as new solid state light sources, are currently undergoing rapid development in the field of lighting. They are fabricated with single garnet phosphors (Y₃Al₅O₁₂:Ce³⁺) and a blue or near-UV LED chip.¹⁻³ Rare earth (RE)-activated luminescent materials are of sizable interest due to their high efficiency and abundant emissions based on level transitions.4-8 Although yellow phosphors are commercially available, the lack of a sufficient red component in the spectra leads to a low color rendering index $(R_a < 0)$ and high color temperature (7750 K), restricting their wide application in high-quality general lighting, such as indoor lighting. 9,10 Hence, to resolve the issue, several promising redemitting phosphors have been applied to effectively increase the color rendering index. There are red-emitting phosphors with single doped activator ions in the host, such as $M_2Si_5N_8:Eu^{2+}$ (M = Ca, Sr, Ba), MAlSiN₃: Eu^{2+} (M = Ca, Sr), (Na, $K, NH^{4+})_2MF_6:Mn^{4+}(M = Ti, Ge, Si, Sn, Ga, Y) and (Ca, Ba, Sr)$ MF₆:Mn⁴⁺(M = Ti, Ge, Si).¹¹⁻¹⁷ Moreover, with the co-doped activator ions and the energy transfer among them, most single-phase white light phosphors can be obtained, such as the

Recently, solid solution phosphors have been widely studied for broadband, color-tunable photoluminescence, which indicates that the regular luminescence can be achieved by changing components of the solid-solution, 25,26 including color-tunable. broadband solid solution $\operatorname{Ca}_{1-x}\operatorname{Li}_x\operatorname{Al}_{1-x}\operatorname{Si}_{1+x}\operatorname{N}_3:\operatorname{Eu}^{2+},$ $(Na_{1-x}Ca_x)(Sc_{1-x}Mg_x)Si_2O_6$ $\operatorname{Ca}_{2+x}\operatorname{La}_{8-x}(\operatorname{SiO}_4)_{6-x}(\operatorname{PO}_4)_x\operatorname{O}_2:\operatorname{Eu}^{2+}$ and $\operatorname{MgGa}_2\operatorname{O}_4-\operatorname{ZnGa}_2\operatorname{O}_4:$ Mn²⁺,Eu³⁺ and so on.^{9,27-29} Namely, the solid solution phosphors, showing gradually controlled blue-yellow zone emission, are obtained by a conventional high-temperature solid-state reaction. However, researchers rarely reported the solid solution phosphors of garnet. Therefore, in the present work, we systematically report synthesis and luminescence properties of color-tunable, broadband $(Lu_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}$ new garnet solid solution phosphors doped with 0.06 mol% Ce³⁺. The emissions of the solid solution phosphors can be tuned continuously from yellow to orange-red. We researched phase structure and luminescence properties solid solution phosphors $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}:Ce^{3+}$ (x = 0-0.2), and observed that the width at half maximum (FWHM) of the emission band broadens with the increase of the MAS. Meanwhile, the PL spectra of the $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}:Ce^{3+}$ phosphors upon blue excitation can yield orange-red emission.

familiar double-doped Eu²⁺–Sm³⁺, Eu²⁺–Mn²⁺, Ce³⁺–Mn²⁺, and triple-doped Tb³⁺–Ce³⁺–Mn³⁺, Eu²⁺–Tb³⁺–Mn²⁺, and so on.¹⁸⁻²⁴ However, such a method in the single host system full-color emission can be realized by designing the activator ions entering different crystallographic sites.

^{*}Research Institute for New Materials Technology, Chongqing University of Arts and Sciences, Chongqing, 402160, China. E-mail: danbaiht@126.com

^bInstitute of High Technology Physics, National Research Tomsk Polytechnic University, Tomsk, 634050, Russia

School of Physics and Opto-Electronic Technology, Baoji University of Arts and Sciences, Baoji, Shaanxi 721016, P. R. China

Experimental

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Synthetic procedures

The main text of the article should appear here with headings as appropriate. $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}:Ce^{3+}$ solid solution phosphors were prepared by conventional solid state reaction method. The raw materials consisted of Tb_4O_7 (99.99%), CeO_2 (99.99%), Al_2O_3 (A. R.), SiO_2 (A. R.) and MnO_2 (A. R.) powders. The x value was varied in the range of 0–0.2. The stoichiometric raw materials were mixed and preheated at $1000\,^{\circ}C$ for 2 h in air, and then the pre-fired products were calcined at $1600\,^{\circ}C$ for 6 h in a reductive atmosphere (H_2 $10\% + N_2$ 90%). Finally, a series of $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}:Ce^{3+}$ solid solutions were obtained with the different percentage of MAS after cooling down to room temperature.

Characterization

The crystal structure of samples were analyzed by X-ray diffractometer (XRD, TD-3500, Dandong, China) with Cu Ka radiation ($\lambda = 1.5406 \text{ Å}$). The cathode voltage and tube current were 30 kV and 20 mA, respectively. The Rietveld refinement of the structure of samples was completed by using the General Structure Analysis System (GSAS) package within the CMPR and EXPGUI interface. The photoluminescence emission (PL) and photoluminescence excitation (PLE) spectra were measured by using a fluorescent spectrophotometer (F-7000, Hitachi, Japan) with a 150 W Xe lamp as the excitation light source. The excitation and emission spectra were scanned in a range of 290-530 nm and 480-680 nm, respectively. The morphology of sample was observed using a transmission electron microscopy (TEM) and high-resolution TEM (HRTEM) analyses (JEM-21000, JEOL, Japan). The room temperature fluorescence decay curves were obtained from a spectrofluorometer (Horiba, Jobin-Yvon Tokyo, Japan) using a tunable pulse laser radiation (nano-LED-450 nm) for the excitation.

Results and discussion

Crystallization behavior and structure

The XRD patterns of $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}:Ce^{3+}$ (x = 0-0.2) are showed in Fig. 1a. All the diffraction peaks of samples match well with single-phase TbAG (JCPDF Card no. 17-0735). It is observed that the solid solutions have been synthesized successfully. With increase $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}$:Ce³⁺, the diffraction peaks shift to larger angles (Fig. 1b). In order to acquire the quantitatively structural evolution of solid solution, the crystallographic data was analyzed by Rietveld refinement. Fig. 2 shows the X-ray Rietveld refinement of $(Tb_{0.9}Mn_{0.1})_3Al_2(Al_{0.9}Si_{0.1})_3O_{12}$:Ce³⁺ and the refined results of $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}$: Ce^{3+} (x=0,0.1, 0.2) were shown in Table 1. The results support that the obtained solid solutions are single-phase structures and belong to the same symmetry and space group $Ia\bar{3}d$ (230). When x rise from 0 to 0.2, the cell parameters (a/c) decrease from 12.074 Å to 12.034 Å, and the cell volume (V) shrinks from 1760.17 Å³ to 1742.8 Å^3 .

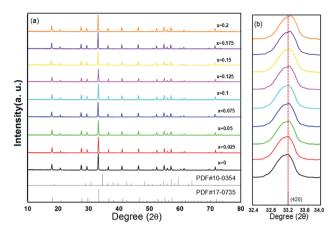


Fig. 1 (a) XRD patterns of $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}$: Ce^{3+} (x=0-0.2) and (b) enlarged XRD patterns within the range of $32.4-34.0^{\circ}$.

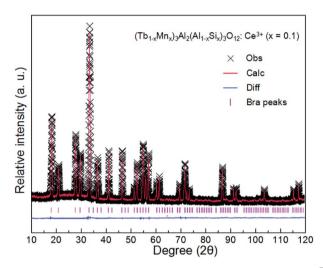


Fig. 2 X-ray Rietveld refinement of $(Tb_{0.9}Mn_{0.1})_3Al_2(Al_{0.9}Si_{0.1})_3O_{12}:Ce^{3+}$

Table 1 Refinement results of $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}:Ce^{3+}$ (x=0, 0.1, 0.2)

	X = 0	X = 0.1	X = 0.2
Crystal system Space group Z Cell parameters/Å $\alpha/\beta/\gamma$ (°) Cell volume (ų)	Cubic $Ia\bar{3}d$ (230) 8 $a/c = 12.074$ 90 1760.17	Cubic $Ia\bar{3}d$ (230) 8 $a/c = 12.051$ 90 1751.72	Cubic $Ia\bar{3}d$ (230) 8 $a/c = 12.034$ 90 1742.8
2θ interval, deg Profile factor $R_{\rm p}$ Weighted profile factor $R_{\rm wp}$	10–120 7.49% 10.12%	10–120 7.25% 10.03%	10–120 8.13% 12.51%

The crystal structural evolution by introducing MAS into TbAG is shown in Fig. 3. According to Bragg's equation ($2d \sin \theta = n\lambda$, where d is the spacing between the planes, λ is the wavelength of the X-ray, and θ is the diffraction angle). Here, Mn²⁺ (0.67 Å, CN = 8) and Si⁴⁺ (0.26 Å, CN = 4) ions have a smaller radius than Tb³⁺ (0.92 Å, CN = 8) and Al³⁺ (0.39 Å, CN = 4) ions. When MAS (cubic, $V = 1573.04 \text{ Å}^3$) is dissolved in

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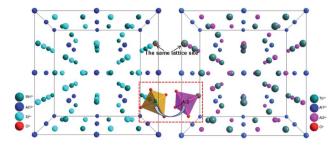


Fig. 3 Crystal structural evolution by introducing MAS (left) into TbAG (right).

TbAG (cubic, $V = 1760.17 \text{ Å}^3$), the (MnSi)⁶⁺ pair will partially substitute the larger (TbAl)⁶⁺ pair, leading to a decline of the spacing between the planes and a shrink of lattice cell. Additionally, with increasing the content of MAS in solid solution, the lattice symmetry will be lowered and the crystalline cell will distort. These changes of crystal structure will have important effects on the photoluminescence of the obtained solid solutions.

The TEM and HRTEM images of $(Tb_{0.9}Mn_{0.1})_3$ - $Al_2(Al_{0.9}Si_{0.1})_3O_{12}$: Ce^{3+} was shown in Fig. 4. The d-spacings of 0.32 nm and 0.49 nm could be assigned to the (321) and (211) planes. The selected-area electron diffraction (SAED) pattern shows the single crystal character of $(Tb_{0.9}Mn_{0.1})_3$ - $Al_2(Al_{0.9}Si_{0.1})_3O_{12}$: Ce^{3+} grain. The EDS elemental analysis (in Fig. 4d) and mappings (in Fig. 5) exhibit that Tb, Mn, Al, Si, and O are very homogeneously distributed within a single crystal particle of the solid solutions.

Photoluminescence characteristics

Under 456 nm excitation, the emission spectra of $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}:Ce^{3+}$ (x=0-0.2) at room temperature, exhibit an obvious broadening trend with a maximum at 544 nm as shown in Fig. 6a. FWHM increases gradually from 68 nm (x=0) to 86 nm (x=0.2) with increasing x, whereas the

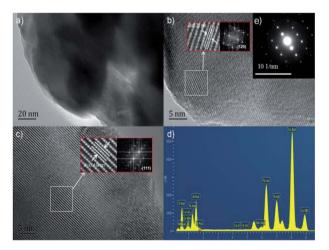


Fig. 4 (a) TEM image and (b and c) HRTEM images of $(Tb_{0.9}Mn_{0.1})_3$ - $Al_2(Al_{0.9}Si_{0.1})_3O_{12}:Ce^{3+}$, (d) EDS pattern detected in (a), and (e) SAED image of (b). Insets are the fast Fourier transforms (FFT) of the relevant HRTEM image sections.

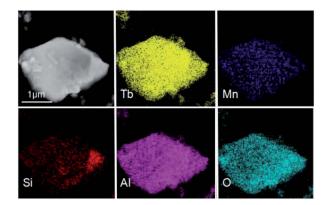


Fig. 5 TEM image and EDS elemental mapping of a $(Tb_{0.9}Mn_{0.1})_3$ -Al $_2(Al_{0.9}Si_{0.1})_3O_{12}$:Ce $^{3+}$ particle.

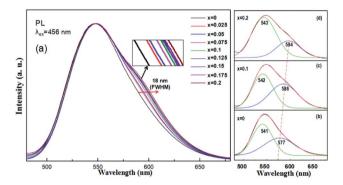


Fig. 6 (a) PL spectra of $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}$: Ce^{3+} (x=0-0.2), and (b-d) Gaussian curve fittings of $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}$: Ce^{3+} (x=0,0.1,0.2).

left wing and peak position remains almost unchanged. The broadening emission bands were achieved with the increase of the MAS concentrations in TAG, which can be ascribed to combine the $5d^1 \rightarrow 4f (^2F_{5/2,7/2})$ transition of Ce^{3+} and the $^4T_1 (t_2^4e) \rightarrow ^6A_1 (t_3^3e^2)$ transition of Mn^{2+} , mainly dependent on energy transfer of $Ce^{3+} \rightarrow Mn^{2+}$ and $Tb^{3+} \rightarrow Mn^{2+}$. At that, the Tb^{3+} ions in the host acted both host and activator and it can show host lattice emission. It is observed that the luminescence spectra of $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}$: Ce^{3+} is a complex band, which presents the mixture of Ce^{3+} , Tb^{3+} and Mn^{2+} luminescence and the Ce^{3+} emission plays the leading role.

As we know, in order to realize asymmetric color-tunable spectral broadening, the $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}:Ce^{3+x}$ solid solution phosphors can be mainly attributed to structural disorder and energy transfer from sensitizer to activator are one of important way. Structural disorder is one of causes for spectral broadening in luminescent materials and can be synthesized by introducing analogous substitution in crystal lattice. That is isostructural with MAS, both crystallizing in a cubic $Ia\bar{3}d$ structure, which makes it possible to introduce MAS into TbAG as a substitution. In addition, the substitution between $(MnSi)^{6+}$ pair and $(TbAl)^{6+}$ pair can be considered as double-doping in TbAG. According to the increases of Mn^{2+}/Tb^{3+} , Si^{4+}/Al^{3+} ratio, the degree of structural disorder also increase. Moreover, the electronic and crystal structure of the

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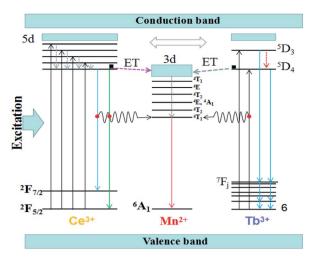


Fig. 7 Schematic energy-level diagram of Ce³⁺, Tb³⁺ and Mn²⁺

solid solution productions $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}$ can be changed, which can affect the spectral tuning. Energy transfer is another reason, which plays an important role in the $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}$ host.

The Fig. 7 shows the schematic energy level for the energy transfer processes of Ce^{3+} , $Tb^{3+} \rightarrow Mn^{2+}$ in the $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}$ host. As a sensitizer, the Ce^{3+} ions can transfer their energy to the activator Mn²⁺ ions, including between the 5d 1 \rightarrow 4f ($^2F_{5/2,7/2}$) of Ce $^{3+}$ and 7F_6 \rightarrow 5D_4 of Tb $^{3+}$ solution transitions. When the solid phosphors $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}:Ce^{3+}$ are excited within the Ce^{3+} absorptions for instance at 456 nm blue light, the electrons of Ce³⁺ ions are firstly lifted from the ground state 4f to the excited state of the 5d. Then, the electrons relax from highest excited state (5d) to lowest excited state (5d) orbitals and release energy in form of yellow lights and eventually return to the ground state 4f (${}^{2}F_{5/2,7/2}$). When the Mn²⁺ dopants are built into, partial energy which is absorbed by Ce3+ groups can be transferred to Mn²⁺ in non-radiative process as well as transfer the lowest activation energy (5D₄) of Tb³⁺ ions to the 3d level of Mn²⁺, and then release energy in form of orange-red lights and eventually return to the ground state ⁶A₁.

In our work, TbAG:Ce phosphors emit bright yellow light due to the $5d^1 \rightarrow 4f (^2F_{5/2,7/2})$ transition of Ce^{3+} ; moreover, the $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}:Ce^{3+}$ solid solution phosphors can emit orange-red light via energy transfer of $Ce^{3+} \rightarrow Mn^{2+}$ in the pictorial diagram Fig. 11b. Thus, it can be realized that the color-tunable emissions shift from yellow light to orange-red light in the solid solution garnets. The Gaussian curve fittings of $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}$: Ce^{3+} (x = 0, 0.2) phosphors are shown in Fig. 6b-d. The curve fittings exhibit that the emission bands consist of two broad bands peaking at 541 nm, 542 nm, 543 nm (Fit Peak 1, green curve) and 577 nm, 586 nm 594 nm (Fit Peak 2, blue curve), respectively. The Fit Peak 1 exhibits that the shift is not obvious; however, the Fit Peak 2 shows obvious red-shift from 577 nm to 594 nm. The luminescence of Mn²⁺ (3d⁵) ions in solids typical exhibits broad band emission with the maxima around 590 nm due to the ${}^{4}T_{1}$ $(t_{2}^{4}e) \rightarrow {}^{6}A_{1}$ $(t_3^3 e^2)$ transition of Mn²⁺. ^{32,33} Therefore, this is attributed to the significant spectral overlap between the emission of $5d^1 \rightarrow 4f$ $(^{2}F_{5/2,7/2})$ transition of Ce^{3+} and the d-d spin-forbidden transition of Mn²⁺. It is almost in agreement with the spectral broadening.

The excitation spectrum of $Tb_3Al_2Al_3O_{12}$: Ce^{3+} (x=0) in the range of 290 to 530 nm (in Fig. 8, black curve) consist of broad band peaked at 327, 375, and 456 nm. Of these, the two stronger bands with peaks at 327 and 456 nm are related correspondingly to the 4f \rightarrow 5d transition of Ce³⁺ ions, and the two weak peaks around 375 nm are ascribed to the $f \rightarrow f$ allowing transition of Tb³⁺ ion. Moreover, the excitation spectrum of (Tb_{0.8}- $Mn_{0.2}$ ₃ $Al_2(Al_{0.8}Si_{0.2})_3O_{12}$: Ce^{3+} (x = 0.2) (in Fig. 8, red curve) indicates three bands peaked at 305, 338, and 466 nm in the range of 290 to 530 nm. As the MAS concentration increases to x = 0.2, the excitation peak has two bands with the maxima at 466 and 338 nm due to the $4f(^2F_{5/2}) \rightarrow 5d^1$ transitions of Ce^{3+} as well as the excitation peak around 305 nm is attributed to the spinforbidden (E₁) transitions of Tb³⁺ cations. In addition, the relative intensity of the two weak peaks around 375 nm distinctly reduces due to the Tb3+ to Mn2+ energy transfer. Meanwhile, the results can indicate a good indicator of the transfer from Ce^{3+} Tb^{3+} Mn^{2+} energy $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}$ host.

The temperature dependence experiment of phosphors illustrated that the thermal quenching is one of the most important parameters applied in wLEDs because it directly affects light output and CRI, and the peak relative emission under intensity 456 nm excitation $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}:Ce^{3+}$ (x = 0, 0.1, 0.2) was depicted in Fig. 9. As shown in Fig. 9, as the temperature increases, the emission intensity of phosphors decreases. In addition, with increasing x values the thermal stability gradually decreases, which can be explained by the neighboring-cation effect.³⁴ While the temperature was increased to 150 °C (~423 K), the peak emission intensities are decreased to 73%, 67% and 61% of the initial value (25 °C).

The real quenching temperature (T50%) is defined as the temperature at which the emission intensity is 50% of its original value. The phosphors have a T50 of over 250 °C,

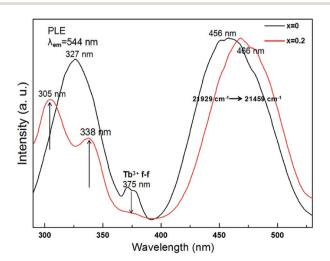


Fig. 8 PLE spectra of $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}:Ce^{3+}$ (x = 0, 0.2).

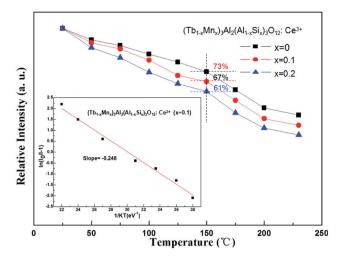


Fig. 9 Temperature-dependent emission intensity of $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}:Ce^{3+}$ ($x=0,\ 0.1,\ 0.2$) phosphors.

suggesting their superior thermal stability as luminescent materials for use in WLEDs. The activation energy (ΔE) of thermal quenching was calculated by the Arrhenius equation:³⁵

$$I(T) \approx \frac{I_0}{1 + A \exp\left(-\frac{\Delta E}{kT}\right)}$$
 (1)

where I_0 is the initial intensity of the emission at room temperature; I is the testing temperature; A is constant and does not influence the calculation; k is the Boltzmann's constant (8.617 × 10^{-5} eV K⁻¹). The inset of Fig. 9 shows the plot of $\ln(I_0/I-1)$ against 1/kT of the synthesized $(\mathrm{Tb}_{1-x}\mathrm{Mn}_x)_3\mathrm{Al}_2(\mathrm{Al}_{1-x}\mathrm{Si}_x)_3\mathrm{O}_{12}:\mathrm{Ce}^{3+}$ (x=0.1), fitted to the thermal quenching data. The estimated value of ΔE was 0.248 eV, which close to value of $\mathrm{Y}_3\mathrm{Al}_5\mathrm{O}_{12}:\mathrm{Ce}^{3+}$ (0.25 eV), showing a better thermal stability.³⁶

In addition, in order to further expound the energy transfer process, the decay curves of the Ce^{3+} ion emission in the $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}:Ce^{3+}$ solid solution phosphors

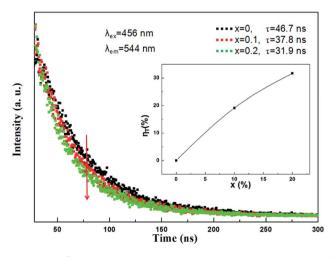


Fig. 10 Room temperature decay curves of $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}:Ce^{3+}$ (x=0, 0.1, 0.2) under excitation at 456 nm and emission at 544 nm. The inset shows the energy transfer efficiency η_T .

under 456 nm excitation and monitored at 544 nm are shown in Fig. 10. In principle, the lifetime of Ce^{3+} can be shortened by the $Ce^{3+} \rightarrow Mn^{2+}$ energy transfer. All of the decay curves can be fitted well with the second exponential equation:

$$I(t) = A_1 \exp(-t/\tau_1) + A_2 \exp(-t/\tau_2)$$
 (2)

where I is the luminescence intensity, A_1 and A_2 are all constants, τ is the time, and τ_1 , and τ_2 represent lifetimes for exponential components, respectively. Namely, the fluorescent dynamics of Ce^{3+} were altered via energy transfer between Ce^{3+} and Mn^{2+} . Furthermore, the effective lifetime constant (τ^*) can be defined as:

$$\tau^* = (A_1 \tau_1^2 + A_2 \tau_2^2) / (A_1 \tau_1 + A_2 \tau_2)$$
 (3)

so the effective decay time values (τ^*) were calculated to be 46.7 ns, 37.8 ns and 31.9 ns for $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}$:Ce³⁺ (x=0,0.1,0.2), respectively. The efficiency of energy transfer (η_T) in the $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}$ host can be calculated following:³⁷

$$\eta_{\rm T} = 1 - \tau_{\rm s}/\tau_{\rm so} \tag{4}$$

here τ_s is the decay lifetime of Ce^{3+} in the presence of Mn^{2+} , and τ_{s_o} is the decay lifetime of Ce^{3+} in the absence of Mn^{2+} , respectively. As shown in the inset of Fig. 10, It can be seen that the efficiency of energy transfer (η_T) gradually increases with the rising Mn^{2+} content, and the value reach approximately 32% at x=0.2. The obtained results confirm the typical effect of the Ce^{3+} $\rightarrow Mn^{2+}$ energy transfer.

The CIE coordinates of $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}$: Ce^{3+} (x=0,0.1,0.2) phosphors were shown in Fig. 11a. The calculated CIE coordinates are (0.4485,0.5073) for x=0, (0.4803,0.4618) for x=0.1 and (0.5011,0.4102) for x=0.2, respectively. We can clearly see that the color shifts red zone conducive to improve the CRIs with increasing x. The digital photos of the

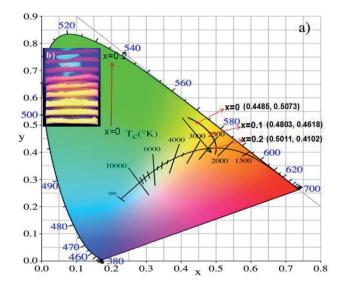


Fig. 11 (a) CIE chromaticity coordinates and (b) digital photos under 365 nm excitation of $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}$: Ce³⁺ (x=0, 0.1, 0.2).

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 $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}$: Ce^{3+} (x = 0, 0.1, 0.2) solid solution phosphors at 365 nm excitation are demonstrated in Fig. 11b. The color of phosphors gradually shifts from yellow light to orange-red light with increase of the MAS content. Then, it can observed that the luminescence $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}$: Ce^{3+} (x = 0.2) has high CRI, and is redder than TbAG:Ce.

Conclusions

summary, a series of color-tunable $(Tb_{1-r}Mn_r)_3$ $Al_2(Al_{1-x}Si_x)_3O_{12}:Ce^{3+}$ garnet solid solution phosphors were successfully synthesized by a solid-state reaction method. With the increase of MAS content, there is no other special impurity phase, which can be compared with values of the cell parameters via the suggested formula. The right wing of PL spectra under the 456 nm excitation exhibit spectral broadening and the FWHM increases gradually from 68 nm to 86 nm. Furthermore, the PLE spectra show spectral shift and new absorption band, which is attributed to change of crystal structure and energy transfer $Ce^{3+} \rightarrow Mn^{2+}$ and $Tb^{3+} \rightarrow Mn^{2+}$. Meanwhile, via fluorescence decay analyses the energy transfer of activators can be proved further. The CIE coordinates shift from (0.4485, 0.5073) to (0.5011, 0.4102), which high CRI. These results indicate $(Tb_{1-x}Mn_x)_3Al_2(Al_{1-x}Si_x)_3O_{12}$:Ce³⁺ garnet solid solution phosphors may be promising for general lighting in future.

Conflicts of interest

There are no conflicts to declare.

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